# MAINTENANCE MANUAL MICROCOMPUTER BOARD 19D902865G1, G3, G4

TABLE OF CONTENTS										
	<u>Page</u>									
SPECIFICATIONS	1									
DESCRIPTION	1									
CIRCUIT ANALYSIS	1 1									
MICROCOMPUTER, LATCH, EPROM AND EEPROM	2									
KEYBOARD INTERFACE	2 2									
LIGHT/DARK SENSOR	23									
FAST SQUELCH DETECTOR	3									
HORNRING	3 3									
MEMORY-MAPPING USING MUX U7	3 3									
TEST PROCEDURES	3									
FLASH PROGRAMMING	3									
PC PROGRAMMING	3									
OUTLINE DIAGRAM	4									
SCHEMATIC DIAGRAM	5									
PARTS LIST	7									
IC DATA	8									

Ericsson Inc. Private Radio Systems Mountain View Road Lynchburg, Virginia 24502 1-800-528-7711 (Outside USA, 804-528-7711



Printed in U.S.A.

# **SPECIFICATIONS\***

#### Input Power

A+ (J6-23) SW A+ (J6-24) +5V (J6-25) Maximum Current Drain	13.8 VDC ±20% 13.8 VDC ±20% 5.0 VDC ±5%
A+ RELAY-CTRL HIGH RELAY-CTRL LOW SW A+ +5V	5 Milliamperes 2 Milliamperes 300 Milliamperes 250 Milliamperes
Temperature Range:	-30°C to +70°C (-22°F to +158°F)
Logic Levels High (1) Low (0) Rise Time Fall Time EL Driver Output (13.8 VDC SW A+) Voltage Frequency Current	4.0 ±1.0 VDC 0.5 ±0.5 VDC 100 Nanoseconds 100 Nanoseconds 125 Volts RMS 400 Hz 15 Milliamperes
(2.7 K load on Relay Control) High Level Low Level	2.5 Volts Minimum 0.5 Volts Maximum
Light Level Detect Upper Hysteresis (Maximum) Lower Hysteresis (Minimum)	2.6 VDC 2.4 VDC
Watchdog Timer Reset Pulse Width	200 Milliseconds (Nominal)
Timeout Period	1.6 Seconds (Nominal)

\* These specifications are intended primarily for the use of the service technician. Refer to the appropriate Specification Sheet in the applicable maintenance manual for the complete specifications.

## **DESCRIPTION**

Microcomputer Board 19D902865 provides the intelligent interface to the Keypad/Display Board and the Input/Output Board. The Microcomputer Board also provides the intelligence necessary to interface with the radio, siren/light/PA unit, the vehicular repeater unit, dual control head and Voice Guard unit.

The Microcomputer Board contains an 80C52 microcontroller with external program memory in a FLASH-EPROM. The Microcomputer also contains an EEPROM containing the control unit (radio system) personality along with the user control settings.

Power up/down control of the control unit and the rest of the radio system is performed by a flip-flop. This flip-flop switches the A+ power to the rest of the radio system through a relay.

AC power for the electroluminescent panel is generated by the EL driver device. This power is duty-cycle modulated to provide the intensity control of the EL backlighting.

The fast squelch detector is comprised of an analog filter/limiter circuit. The fast squelch detector provides a quick indication of carrier activity on the receive radio channel.

Ambient light level from the phototransistor on the Keypad/Display Panel is limited by a voltage comparator. This is used to automatically turn on the EL backlighting and reduce the LED brightness.

An optional limited channel guard signal from the radio is re-limited by a comparator. The Microcomputer Board performs the channel guard (tone or digital) decoding in the radio system.

A holding register is used to buffer data to the Keypad/Display Board. This provides isolation and drive of the signals to the Keypad/Display Board.

A second holding register is used to buffer data to the Input/Output (I/O) Board. This provides isolation and drive of the signals to the I/O Board.

A decoder is used to generate a gated write pulse to the holding registers on the Microcomputer Board and other registers on the I/O Board.

The watchdog timer is used to provide a control unit reset pulse. The watchdog timer is used to monitor the microcomputer software execution.

# **CIRCUIT ANALYSIS**

The Microcomputer Board represents the heart of the control unit. It contains the microcomputer, firmware and personality data required to operate the unit. Display data is output to the display board and keypad inputs are received through J1. Interface to the Input/Output Board is through a 26-pin ribbon cable (connector J6).

Figure 1 shows a block diagram of the digital input/output devices. The data bus (U1-36 through U1-43) acts as a parallel port when writing to U5 and U6. U7 is a decoder that is used to provide the memory mapping of U5, U6 and addition I/O on the I/O Board.

## **POWER RELAY CONTROL CIRCUIT**

The power control for the control unit is performed by flip-flop U8.1 and associated circuitry. The power control flipflop turns on and off the power relay on the Input/Output Board which supplies the switched battery power (SW A+) from the raw continuous battery power (A+).

The output control signal to route A+ to SW A+ on the I/O board is RELAY-CTRL (J6-12). When RELAY-CTRL is high, the relay on the I/O board is turned on (closed) and supplies power to SW A+. When RELAY-CTRL is low, the relay on the I/O board is turned off (opened) and no power is supplied on SWA+.

The relay control flip-flop is powered from the continuous battery power (A+). This ensures that starting from a powered down condition, the control unit can be powered up from the front panel (keypad board).

When the control unit is initially powered down (SW A+, +5V, and RELAY-CTRL are at zero volts but continuous battery power is running on A+), the board is turned on by grounding

Copyright © April 1992, Ericsson GE Mobile Communications Inc

Zener diode VR5 and diode D4 insure the pass transistor Q3 turns on only when Q = 0 irrespective of spikes on A+.

The intelligence of the control unit is contained in the microcomputer U1. The microcomputer is an 80C52 - 8 bit controller. U1 is a high performance CMOS processed part, utilizing internal timers and a serial interface on a priority interrupt structure. The internal CPU handles the Boolean processing, internal bit and byte RAM addressing, instruction fetching and execution and interface to the external world by means of 16 dedicated I/O lines along with an 8 bit bussed memory-mapped I/O.

Microcomputer U1 operates at an internal clock instruction cycle time of 11.0592 MHz (nominal). The clock frequency is determined by quartz crystal Y1, which provides a fundamental mode of operation, and capacitors C51 and C52, which provide start up time and frequency stability over the specified temperature range.

The microcomputer accesses program memory information from the FLASH-EPROM U3. The FLASH-EPROM (EPROM) is a 64K by 8 bit programmable read-only-memory device. This device contains both the operational instruction code for the CONTROL UNIT normal mode of operation as

### LBI-38726

the PWRSW (J1-3). This turns on transistor Q2. The collector of O2 is pulled up to A+ causing a rising edge to the clock input of flip-flop U8.

The rising edge causes the flip-flop U8-1 to change state from Q = 0 to Q = 1. The Q output becomes Q = 0, thereby turning on pass transistor Q3 and allowing continuous A+ to be sent to RELAY-CTRL and onto the I/O Board to activate the power control relay. A subsequent press of the power switch will generate another rising edge to the clock input of the flip-flop, thereby toggling its state from Q = 1 to Q = 0 (Q becomes Q = 1). With Q = 1, pass transistor Q3 turns off which removes continuous A+ from RELAY-CTRL turning off the power control relay on the I/O Board.

Resistor R35 and capacitor C33 provide a hysteresis feedback to the input of the flip-flop. This hysteresis provides debounce on the PWR button (PWSW) in order to prevent chatter on the power up and power down due to mechanical switch bounce.

Resistor R31, diode D1 and capacitor C31 provide filtering on the A+ power to the relay control flip-flop. This filtering prevents the ignition noise and spurious battery voltage drops from changing the state of the relay control flip-flop.

Resistor R32, diode D2 and capacitor C32 provide filtering on the A+ power used in the generation of the clock pulse to the flip-flop.

#### MICROCOMPUTER, LATCH, EPROM AND **EEPROM CIRCUITS**

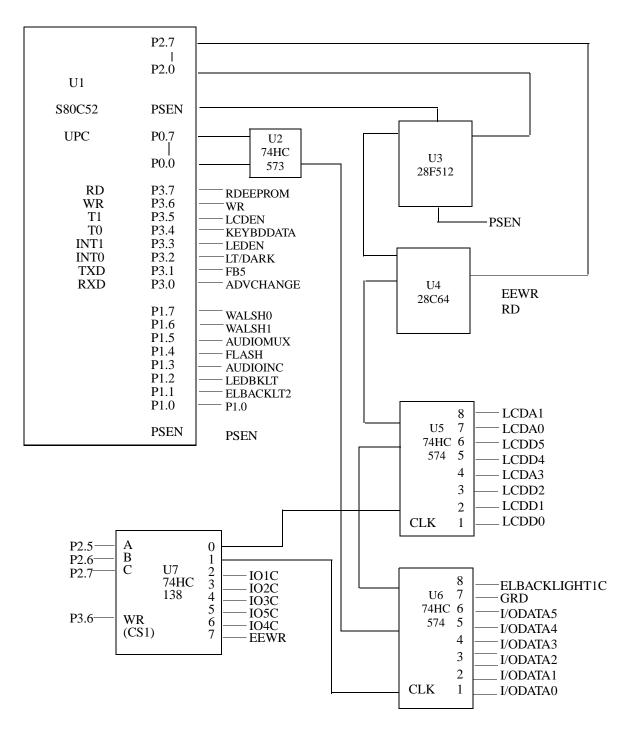


Figure 1 - Digital Block Diagram

well as the test code necessary to implement the test and control **F** functions.

Each access to the EPROM for program memory information is proceeded by an address setup to the EPROM. The high order 8 bits of the address are held stable on lines A8 through A15. Lines A8 through A14 are routed to the EPROM high order address inputs. Address line A15 (P2.7) is routed to the EPROM through U14 which is also used in the flash programming of the EPROM. The low order 8 bits of the address are latched and held stable by the address holding latch U2. The low order address lines are latched on a high to low going pulse on the ALE line. After the address is held stable, the microcomputer issues a low going pulse on PSEN to read the 8 bit program memory information contained in the EPROM at the specified address.

Settings for the radio personality and control unit are contained in the EEPROM U4. The EEPROM is an 8K by 8 bit electrically erasable programmable read-only-memory. This device provides nonvolatile storage of radio personality and user controlled settings. Each access to the EEPROM for personality information is preceded by an address setup to the EEPROM.

The high order 8 bits of the address are held stable on lines A8 through A15. Lines A8 through A12 are routed to the EEPROM high order address inputs. The low order 8 bits of the address are latched and held stable by the address holding latch U2. The low order address lines are latched on a high to low going pulse on the ALE line. After the address is held stable, the microcomputer issues a low going pulse on RD (to read) or WR (to write) the 8 bit personality information from or to EPROM at the specified address.

Device U13 and associated circuitry provide the gated write pulse to EEPROM (U4-27). The gated write pulse is generated from the microcomputer on the signal line WR (U1-18).

Address lines A9 through A12 are gated into U13 to provide an enable to the address decoder U7. The lower order 512 bytes are writable by the microcomputer

In order to write the remaining locations, a PC programmer cable must be installed whereby the control line EEWREN (J6-14) is grounded, thereby allowing writing to all EEPROM locations. When EEWREN is low, diode D3 is low, pulling the inhibit control to U7 low.

Holding register U5 interfaces with the keypad boards to read keypad closure information, activate LEDs and update the LCD display. U5 is accessed via a memory-mapped write to address location 0000 hex.

Holding register U6 interfaces with the I/O board to read radio status and input information, to write radio control information and to route audio paths between the radio and the control unit. U6 is accessed via memory-mapped write address location 2000 hex.

# **KEYBOARD INTERFACE CIRCUITS**

In addition to U5, there are five lines on the microcomputer that interface with the keypad boards. They are LEDBKLT, FLASH, LEDEN, LCDEN and KEYBDDATA.

The holding register U5 latches the data lines to the keypad board. This 8 bit data is used to turn on and off LEDs, setup characters to be written to the LCD display and clock out the sampled keypad closure information to the microcomputer.

# WATCHDOG TIMER CIRCUIT

The watchdog timer U11 is used to monitor the operation of the microcomputer software. It generates a reset pulse in the unlikely condition that the microcomputer goes awry and does not execute the program memory software properly.

The watchdog timer consists of a MAX695 integrated circuit. The microcomputer services the watchdog timer at the WDI input (U11-11). The service line is derived at WDT. Presently resistor R79 is installed (R78 removed), allowing servicing to occur through U6-19 (I/ODATA0). The microcomputer toggles WDT at least every 1.6 seconds to prevent the watchdog timer from timing out and generating a board reset. If a hardware or software failure occurs such that U11 is not serviced, a 200 millisecond reset pulse is generated at U11-16. This reset pulse is or'ed with the power on reset from the I/O board (J6-26 and inverted through Q5) by U13.4 and sent to the microcomputer at U1-10.

# LIGHT/DARK SENSOR CIRCUIT

The outside ambient light level is detected by the microcomputer via the LT/DARK (U1-14) signal derived from the light level detect circuitry consisting of comparator U10 and associated circuitry.

LT/SENSOR is an analog signal (0 to 5 Volts) inputted to the negative input of U10. As the ambient light level increases in intensity, the LT/SENSOR signal increases in level. Resistor R61 provides a load for the analog level derived from the emitter of the phototransistor on the keypad board. Capacitor C21 provides light level filtering. The load value of R61 was chosen to obtain a nominal ambient light threshold detect at approximately 4 to 5 milliwatts/(cm\*cm).

The positive input of U10 is set up with a nominal DC bias level of 2.5 Volts. This bias level fixes the nominal threshold point.

Resistor R62 provides a small level of hysteresis for the detection of the ambient light level. This is used to prevent the comparator from oscillating at light levels near the nominal threshold detect setting.

As the light level increases from a dark condition to a strong light level (0 towards 5 Volts), LT/DARK will start at +5 Volts (due to the internal pull up on the microcomputer) and will flip to 0

Volts as the LT/SENSOR signal passes the 2.5-Volt reference. As the light level decreases from a strong light to a dark condition (5 Volts toward 0 Volts), LT/DARK will start at 0 Volts and will flip to +5 Volts when the LT/SEN\$OR signal passes the 2.5 Volt reference.

#### **CHANNEL GUARD LIMITER CIRCUIT**

The microcomputer detects the channel guard information on the receiver radio frequency channel. The limited channel guard signal is derived from the radio and again is limited by U10 and buffered by Q9. The microcomputer samples the channel guard signal through AUDIOMUX (U1-7) and is controlled by transistor Q8.

Bias on U10 is set at a nominal 2.5 Volts for detecting the channel guard signal from the radio. U10 serves to buffer and re-threshold the signal received from the radio over the long cable

#### FAST SOUELCH DETECT CIRCUIT

The fast squelch detect circuit on the microcomputer board is used to provide a quick detection of carrier activity on a receiver radio frequency channel. This quick detection is used in SCAN operation to lock onto a high priority incoming call. The bias used in the detection of carrier activity is noise squelch.

The fast squelch circuit consists of a three-pole high pass filter, an averaging detector, a DC amplifier and a trigger. The fast squelch circuit is used to provide a fast indication of carrier activity on a channel by monitoring the channel received noise component in the 6000 to 8000 Hz range.

A high pass filter, consisting of C61, C62, R81, R82 and U9, removes all voice signals (0 to 3000 Hz) from the incoming received signal on FASTSO (J6-17). The output signal of the high pass filter (which consists of noise outside of the voice audio band in the range of 6000 to 8000 Hz) is sent to the averaging detector stage.

Noise in the 6000 to 8000 Hz band is applied to the averaging detector which consists of R83, R84, R85, R86, R87, C63, C64, C71 and U9. The noise is rectified to provide an average DC output level proportional to the noise input. A large noise level provides a larger DC output level.

The average DC level is amplified by C72, R88, R89 and U9 to produce a level ranging from 0 to 5 Volts DC. This amplifier buffers the amplified DC level to the input of the trigger.

The trigger consists of R90, R91, C73 and U9. The inverting input of U9 is referenced to BIAS (2.5 Volts DC). When the DC level exceeds 2.5 Volts the U9 trigger switches and provides a positive voltage to transistor Q11 (if enabled by transistor Q10). For a large noise component in the 6000 to 8000 Hz range, U9 saturates at the high level. The output of transistor Q11 is read by the microcomputer on AUDIOMUX U1-7) when selected (during audio mux read multiplexing).

#### **GESTAR GENERATION**

On some control unit applications, P1.6 and P1.7 of the microcomputer are used to generate GESTAR signalling (TONE) for injection into the transmit path.

#### HORNRING CIRCUIT

#### Positive Or Negative Hornring Detect (P11 on J11-2 and J11-3)

The hornring circuit allows the software to look for either a positive (A+) active or negative (A-) active signal. PC programming denotes which polarity is the active state. Note that the audio mux line at the connector (J6-16) Must be floating, I/ODATA4 = 0, I/ODATA5 = 1 and CGRD = 1 in order to read the input.

The following describes the proper setup to read the HORN-RING input correctly.

Positive active (AUDIOMUX = 1 as input):

HORNRING	<u>P1.6</u>	<u>P1.7</u>	AUDIOMUX
A+	0	1	0
float	0	1	1
Negative active (	P1.7 = 1 as	input):	
A-	1	0	NA
float	1	1	NA

Positive Hornring Detect

(P11 on J11-1 and J11-2)

The hornring circuit allows detection of positive (A+) active hornring inputs only. The positive active input hornring is read via J6-16 floating, I/ODATA4 = 0, I/ODTAT5 = 1 and CGRD = 1. (P1.6 and P1.7 are not used.)

#### **ELECTROLUMINESCENT (EL) PANEL DRIVER CIRCUIT**

The electroluminescent (EL) panel driver is a voltage converter that transforms the SW A+ input to a 125 VRMS AC signal.



This transformer must be terminated in an equivalent circuit in order not to cause damage. The equivalent circuit is a 33K ohm resistor in parallel with a 0.068 F capacitor.

The intensity of the EL panel backlighting is changed by varying the duty cycle of ELBACKLT (U6-19). The duty cycle varies from 100 percent (fully on) to 0 percent (fully off) with a cycle time of about 20 milliseconds.

When ELBACKLT1 is high, transistor Q12 is turned on, thereby turning on the pass transistor Q13 which supplies SW A+ power to the EL driver U12. The EL driver accepts the SW A+ input power and generates the nominal AC power required for the EL panel on the keypad board. The EL driver U12 generates the AC power at a specified frequency.

Compensation is provided in the EL driver for degradations over time in the capacitive load of the EL panel. Resistors R114, R115, R116 and capacitors C36 and C42 provide input filtering to the EL driver.

ELBACKLT2 is not presently used (resistor R117 not installed).

# **MEMORY-MAPPING USING MUX U7**

Refer to Table 1 which shows control unit external device memory-mapping of the microcomputer.

MEMORY ADDRESS (HEX)	PSEN	RD	WR	DEVICE ACCESSED
0000 - FFFF E000 - FFFF E000 - E1FF 0000 2000 4000 6000 8000 C000 A000	0 1 1 1 1 1 1 1 1 1	1 0 1 1 1 1 1 1 1	$ \begin{array}{c} 1 \\ 1 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0$	EPROM U3 EEPROM U4 (RD) EEPROM U4 (RD/WR) REGISTER U5 REGISTER U6 I/O BD IO1C I/O BD IO2C I/O BD IO3C I/O BD IO4C I/O BD IO4C I/O BD IO5C

#### Table 1 - Microcomputer Memory-Mapping

The upper three address lines A13, A14 and A15 (U1-26 through U1-28) are used as address inputs U7-1 through U7-3) for U7. The select CS2 line (U7-5) is decoded to prevent writing to the EEPROM U4 address above E1FF Hex. The select CS1 (U7-4) signal is the microcomputer WR (U1-18) signal that is memory mapped to address the various I/O devices (U5, U6 and IO1C through IO5C).

### WRITING TO PARALLEL OUTPUT REGIS-**TER U5 AND U6**

Writing to register U5 and U6 (74HC574 OCTAL D FLIP-FLOP) is accomplished by providing data on the address bus AD0 through AD7 and then activating the Y0 or Y1 signal (WR from U7). The truth table for U5 and U6 is as follows:

PC Programming of the U4 EEPROM is accomplished via the PC Programmer cable and TQ3310 Serial Programming Adapter. Programming of all locations of the EEPROM is executed through a proprietary serial communications protocol. The PC Programmer cable grounds the EEWREN to enable writing to any address location of the U4 EEPROM.



This is accomplished by raising the EEWREN line (6-14) to +12 Volts. The +12 Volts is routed to the flash EPROM (3-1) and to the voltage divider R65/R66. The PFI input of the watchdog timer (U11-9) compares the level of the EEWREN line to be above 8.6 Volts. When EEWREN exceeds 8.6 Volts. the PFO output (U11-10) goes high. This places the microcomputer in the bootrom mode of operation. In this mode, the microcomputer can program the flash memory U3 via a proprietary serial communications protocol. Comparators U10.3 and U10.4 generate a reset pulse whenever the PFO output of U11 goes from a high to a low or vice-versa. The comparators use the transition region at about 1.6 to 3.3 to generate a reset out. Resistor R45 and capacitor C12 slow the edge at PFO so that the comparators can generate a reset pulse of at least 5 microseconds in duration.

LBI-38726

OPERATING MODE	INPUTS	OUTPUTS
	Y Dn	QN
LOAD "1" LOAD "0"	$ \begin{array}{c} \uparrow & 1 \\ \uparrow & 0 \end{array} $	1 0

 $\uparrow$  = Low To High Clock Transition

Dn = Logic Level Prior To Clock Transition

# **TEST PROCEDURES**

A functional System Test Procedure for the microcomputer board consists of exercising the board using a standard "dumb" terminal. This test uses the software that is part of the microprocessor on the microcomputer board to make power and continuity checks, check the keypad/display panel and provide functional checks for the microcomputer and I/O boards.

An additional test procedure is available (where applicable) that uses the S-800 Automatic Tester. For complete information on this procedure, refer to Automatic Tester maintenance manual, LBI-38166.

# **FLASH PROGRAMMING**

The microcomputer board is capable of receiving future software upgrades and feature enhancements via flash programming of the EPROM U3.

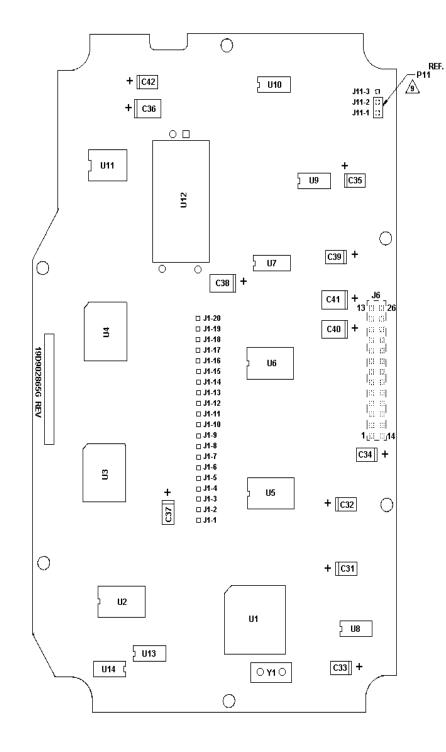
# PC PROGRAMMING

#### LBI-38726

# **OUTLINE DIAGRAM**

SOLDER SIDE

COMPONENT SIDE



J11/P11 JUMPER CHART							
POSITION FUNCTION GR							
1 AND 2	POSITIVE HORN RING	4					
2 AND 3	POSITIVE OR NEGATIVE HORN RING DETECT	1&3					

R53, R54, R55, R78, R91, R117 NOT USED IN GROUPS 1 & 3.

THE FOLLOWING ITEMS ARE MOS DEVICES RE-QUIRING SPECIAL CARE: U1-U8, U11, U13 AND U14.

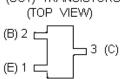


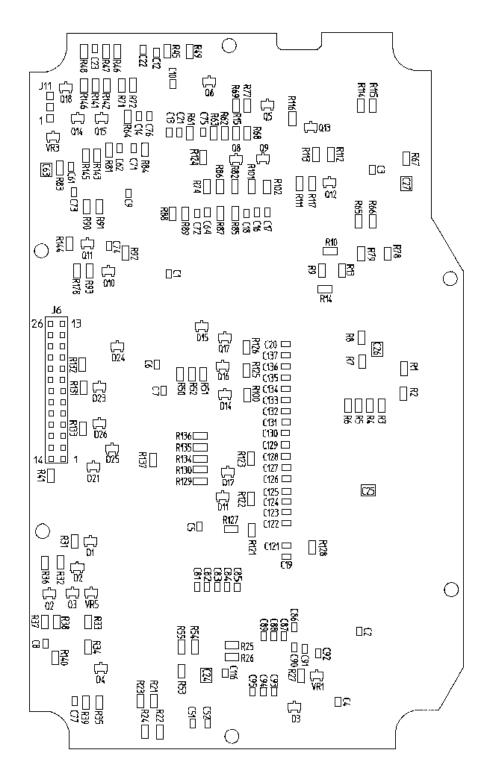
ELECTROSTATIC SENSITIVE DEVICES

LEAD IDENTIFICATION FOR D1, D2, D4, D11, D12, D14, D15, D21, D23-D26, VR1, VR3, AND VR5 (SOT) DIODES (TOP VIEW)



LEAD IDENTIFICATION FOR Q1, Q2, Q3, Q5, Q6, AND Q8 - Q18 (SOT) TRANSISTORS (TOP VIEW) (B) 2 너



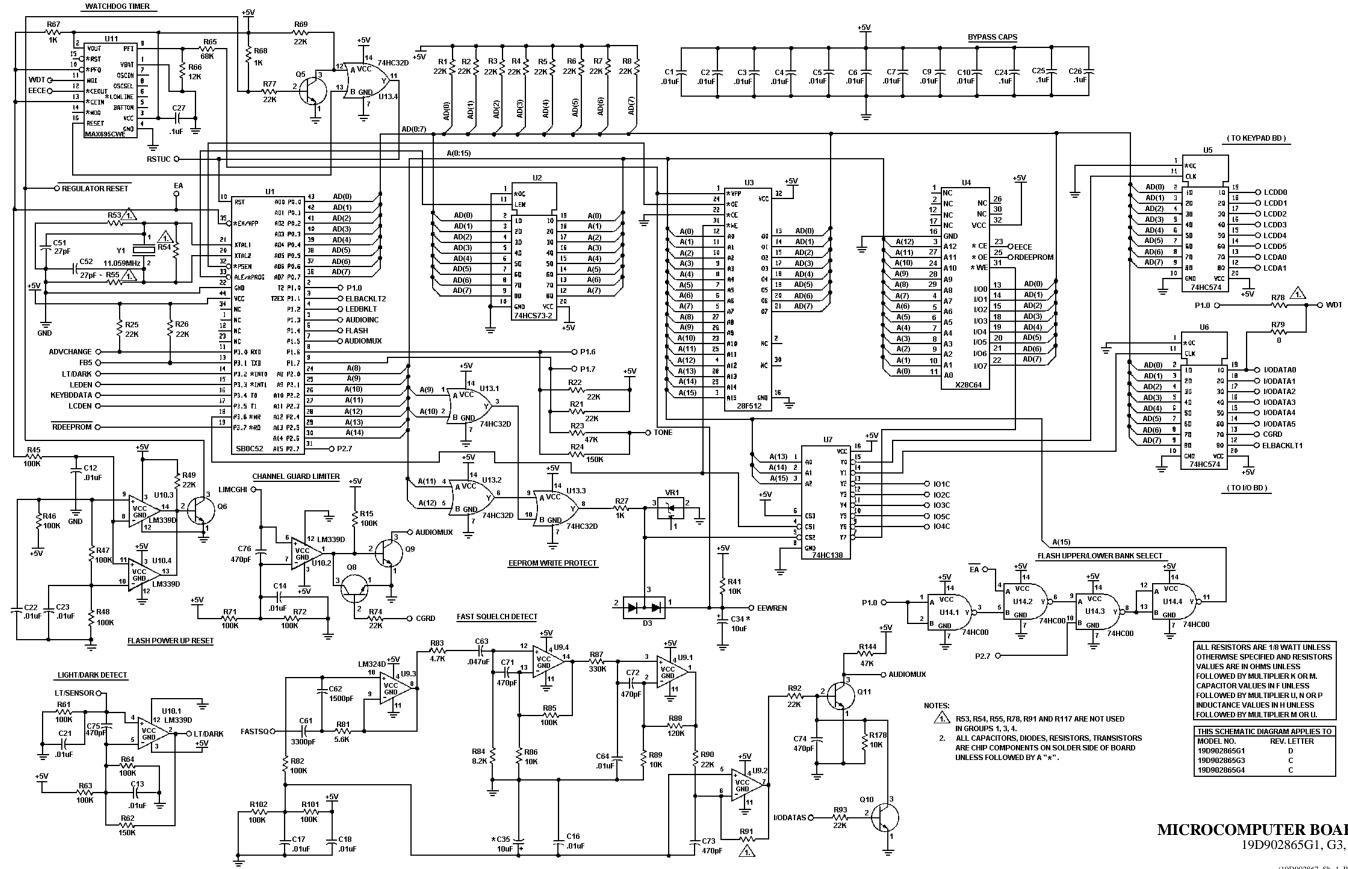


(19D902865, Sh. 1, Rev. 6)

#### MICROCOMPUTER BOARD 19D902865G1, G3, G4

(19D902865, Sh. 1, Rev. 6)

#### SCHEMATIC DIAGRAM

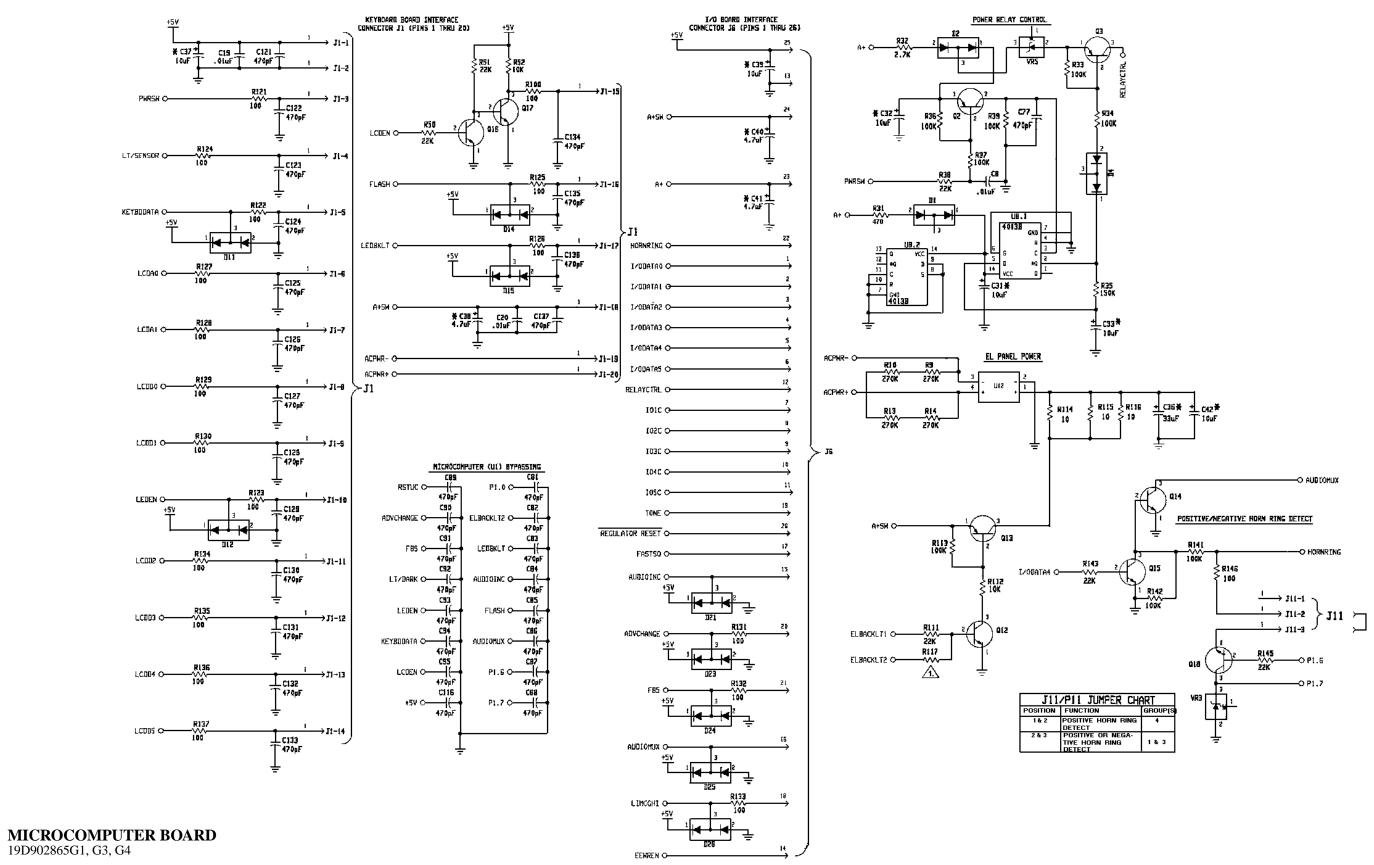


#### LBI-38726

#### MICROCOMPUTER BOARD 19D902865G1, G3, G4

(19D902867, Sh. 1, Rev. 4)

# SCHEMATIC DIAGRAM



(19D902867, Sh. 2, Rev. 4)

CROCOMPUTER BOARD 19D902865G1 - CONV. 19D902865G3 - EDACS 19D902865G4 - SPECIAL ISSUE 2

SYMBOL	PART NO.	DESCRIPTION						
C1 thru C10	19A702052P14	Ceramic: 0.01 uF ±10%, 50 VDCW.						
C12 thru C14	19A702052P14	Ceramic: 0.01 uF ±10%, 50 VDCW.						
C16 thru C23	19A702052P14	Cerámic: 0.01 uF ±10%, 50 VDCW.						
C24 thru C27	19A702052P26	Ceramic: 0.1 uF ±10%, 50 VDCW.						
C31 thru C35	19A705205P6	Tantalum: 10 uF ±20%, 16 VDCW; sim to Sprague 293D.						
C36	19A705205P15	Tantalum: 33 uF ±20%, 16 VDCW; sim to Sprague 293D.						
C37	19A705205P6	Tantalum: 10 uF $\pm 20\%$ , 16 VDCW; sim to Sprague 293D.						
C38	19A705205P18	Tantalum: 4.7 uF ±20%, 35 VDCW; sim to Sprague 293D.						
C39	19A705205P6	Tantalum: 10 uF ±20%, 16 VDCW; sim to Sprague 293D.						
C40 and C41	19A705205P18	Tantalum: 4.7 uF ±20%, 35 VDCW; sim to Sprague 293D.						
C42	19A705205P6	Tantalum: 10 uF ±20%, 16 VDCW; sim to Sprague 293D.						
C61	19A702052P8	Ceramic: 3300 pF ±10%, 50 VDCW.						
C62	19A702052P6	Ceramic: 1500 pF ±10%, 50 VDCW.						
C63	19A702052P22	Ceramic: 0.047 uF ±10%, 50 VDCW.						
C64	19A702052P14	Ceramic: 0.01 uF ±10%, 50 VDCW.						
C71 thru C77	19A702052P3	Ceramic: 470 pF ±10%, 50 VDCW,						
C81 thru C95	19A702052P3	Ceramic: 470 pF ±10%, 50 VDCW.						
*C96	19A705205P6	Tantalum: 10µF ±20%, 16VDCW: sim to Sprague 293D.						
C116	19A702052P3	Ceramic: 470 pF ±10%, 50 VDCW.						
C121 thru C137	19A702052P3	Ceramic: 470 pF ±10%, SG VDCW.						
		DIODES						
D1 and D2	19A700053P2	Silicon: 2 diodes in series; sim to BAV99.						
03	19A705377P4	Silicon: Hot Carrier, 70 PfV; sim to Siemens BAS70-04.						
D4	19A700053P2	Silicon: 2 diodes in series; sim to BAV99.						
D11 and D12	19A700053P2	Silicon: 2 diodes in series; sim to BAV99.						
D14 and D15	19A700053P2	Silicon: 2 diodes in series; sim to BAV99.						
D21	19A700053P2	Silicon: 2 diodes in series; sim to BAV99.						
D23 thru D26	19470005322	Silicon: 2 diodes in series; sim to BAV99.						
		JACKS						
J 1	19A703248F15	Post: Gold Plated, 21 mm length.						
J6	19A702333P54	Connector, printed wiring, two part: 26 pins, rated i amp; sim to Dupont 78207-110.						
J11	19A703248P11	Post: Gold Plated, 10 mm length.						
		LELETED OR CHANGED BY PRODUCTION CHAN						

SYMBOL PART NO. DESCRIPTION **P1**1 9A702104P2 Connector: 2 Position Shorting, Gold Plated; sim to Berg 65474-003. - - - - - - - TRANSISTORS - - - - - - - -9A700059F2 Silicon, NPN: sim to MMRT3905. Q2 and Q3 9A700076P2 Silicon, NPN: sim to MMBT3904, low profile. Q5 and Q6 19A700076P2 Silicon, NPN: sim to MMBT3904, low profile. Q8 thru Q12 9A703197P2 Q13 Silicon, FNF: sim to MMBT4403, low profile. Q14 thru Q18 19A700076P2 Silicon, NPN: sim to MMBT3904, low profile. -----RI thru R8 9B800607P223 Metai film: 22K ohma ±5%, 1/8 w. 9B800607P274 Metal film: 270K ohms ±5%, 1/8 w. R9 and R10 R13 and R14 988006079274 Metal film: 270K ohms ±5%, 1/8 w. R I 5 9B800607P104 метаl film: 100K ohms ±5%, 1/8 w. R21 and R22 19B800607P223 Metal film: 22K ohms ±5%, 1/8 w. R23 19B800607P473 Metal film: 47% ohms ±5%, 1/8 w. R24 1988006079154 Metal film: 150K ohms ±5%, 1/8 w. R25 19B800607P223 Metal film; 22K ohms ±5%, 1/8 w. and R26 R27 19B800607P102 Metal film: 1K ohms ±5%, 1/8 w. \*R31 19B800607P471 Metal film: 470 ohms, 25%, 1/8 w. R32 Metal film: 2.7K ohmas ±5%, 1/8 w. 19B800607P272 R33 and R34 988006079104 Metal film: 100K ohms ±5%, 1/8 w. R35 19B800607P154 Netal film: 150K ohms ±5%, 1/8 w. R36 and R37 198800607P104 Metal film: 100K ohms ±5%, 1/8 w. R38 19B800607P223 Metal film: 22K ohms ±5%, 1/8 w. R39 19B800607F104 Metal film: 100K ohms ±5%, 1/8 w. R41 19B800607P103 Metal film: 10K ohms ±5%, 1/8 w. R45 thr R48 9B800607P104 Metal film: 100K ohms ±5%, 1/8 w, 19B800607P223 R49 thru R51 Metal film: 22K ohms ±5%, 1/8 w. R52 19B800607P103 Metal film: 10K ohms ±5%, 1/8 w. R61 19B800607P104 Metal film: 100K ohms  $\pm 5\%$ , 1/8 w. R62 1988006072154 Metal film: 150K ohma ±5%, 1/8 w. 19B800607P104 Metal film: 100K ohms ±5%, 1/8 w. R63 and R64 R65 9B800607F683 Metal film: 68K ohms ±5%, 1/8 w. R66 1988006079123 Metal film: 12K ohms ±5%, 1/8 w. R67 and R68 19B800607F102 Meta! film: 1K ohms ±5%, 1/8 w. R69 BB800607P223 Metal film: 22K ohms ±5%, 1/8 w. R71 алф R72 19B800607F104 Metal film: 100K ohms ±5%, 1/8 w.

#### DESCRIPTION SYMBOL PART NO. R74 988006079223 Metal film: 22K ohms ±5%, 1/8 w. R77 1988006071223 Metal film: 22K ohms ±5%, 1/8 w. R79 9B800607Pl Metal film: Zero ohms ±5%, 1/8 w. R.\$ 1 988006078562 Metal film: 5.6K ohms ±5%, 1/8 w. R82 9B800607P104 Metal film: 100K ohms ±5%, 1/8 w. R83 988006078472 Metal film: 4.7K ohms ±5%, 1/8 w. **R84** 9B800607P822 Metal film: 8.2K ohms ±5%, 1/8 w, 885 9B800607P104 Metai film: 100K ohms ±5%, 1/8 w. R86 9B800607P103 Metal film: 10K ohms ±5%, 1/8 w. R87 988006072114 Metal film: 330K ohms ±5%, 1/8 w. **R8B** 9B800607P124 Metal film: 120K ohms ±5%, 1/8 w. R89 988006072103 Metal film: 10K ohms ±5%, 1/8 w. R90 988006079223 Metal film: 22K ohms ±5%, 1/8 w. R92 and R93 98800607P223 Metal film: 22K ohms ±5%, 1/8 w. R100 988006079101 Metal film: 100 ohus ±5%, 1/8 w. 98800607P104 Metal film: 100K ohms ±5%, 1/8 w. R101 and R102 R111 98800607F223 Metal film: 22K ohms ±5%, 1/8 w. R112 9B800607F103 Metal film: 10к ohms ±5%, 1/8 w. R113 98800607P104 Metal film: 100K ohms ±5%, 1/8 w. R114 thru R116 98800607P100 Metal film: 10 ohms ±5%, 1/8 w. R121 thru R137 988006079101 Metal film: 100 ohms ±5%, 1/8 w. B800607P154 Metal film: 150k ohms, ±5%, 1/8w. \*R140 R141 and R142 9B800607F104 Metal film: 100K ohms ±5%, 1/8 w. R143 98800607P223 Metal film: 22K ohms ±5%, 1/8 w. R144 98800607F473 Metal film: 47K ohms ±5%, 1/8 w. Metal film: 22K ohms ±5%, 1/8 w. R145 988006072223 R146 9B800607P101 Metal film: 100 ohms ±5%, 1/8 w. R178 9B800607P103 Metal film: 10K ohms $\pm 5\%$ , 1/8 w. - - - - - INTEGRATED CIRCUITS - - - - -UŁ 19A705557P6 Digital: CMOS 8-Bit Microcomputer; sim to Harris IS80052. U2 9A703471P318 Digital: CMOS Octal 3-State Non-Inv Latch; sim to 74HC573-2. 9A705710G15 U3 EPROM KIT (Flash Memory). (Used in Group 1). **U**3 9A14993504 EPROM KIT (Flash Momory). (Used in Group 3). U3 9A705963P2 EPROM: CMOS $512K(64 \times 8)$ Flash Memory; sim to Intel N28F512-200 FIC4. (Used in Group 4). U4 9A149755F2 EEPROM: CMOS SK x 8; sim to Xicor X28054. 9A704380P316 U5 and U6 Digital: CMOS Octal Data Flip-Flop; sim to 74HC574. U7 9A703471P320 Digital: CMOS 3 to 8 Line Decode/Demux; sim to 74HC138. US 9A700029P509 Digital: CMOS Dual Data Flip-Flop; sim to 40136. U9 9A702293F1 Linear: Quad Op Amp; sim to LM324D. U10 9A704125P1 Linear: Quad Voltage Comparator; sim to 19339D. U1 i 9A149895P1 Digital: CMOS Supervisory Circuit; sim to MAX691C. U12 9A149417P2 Driver, Electroluminescent; sim to Endicott Research E746. U13 9A703483P311 Digital: CMOS Quad 2-Input OR Gate; sim to 74HC32D. U14 9A703483P302 Digital: CMOS Quad 2-Input NAND Gate: sim to 74HC00.

# PARTS LIST

```
LBI-38726
```

SYMBOL	PART NO. DESCRIPTION							
VRI	1947000830101	Silicon, Zener: 4.7 Volts; sim to BZx84-C4V7.						
VR3	19A700083P101	Silicon, Zener: 4.7 Volts: sim to BZx84-C4V7.						
VR5	19A700083P101	Silicon, Zener; 4.7 Volts; sim to BZx84-C4V7.						
YI	194702511015	CRYSTALS						
	19470151601	Plate, Insulating, (For Crystal Y1.)						
	19870(STOP)	riate, insulating. (For Crystal II.)						

#### PRODUCTION CHANGES

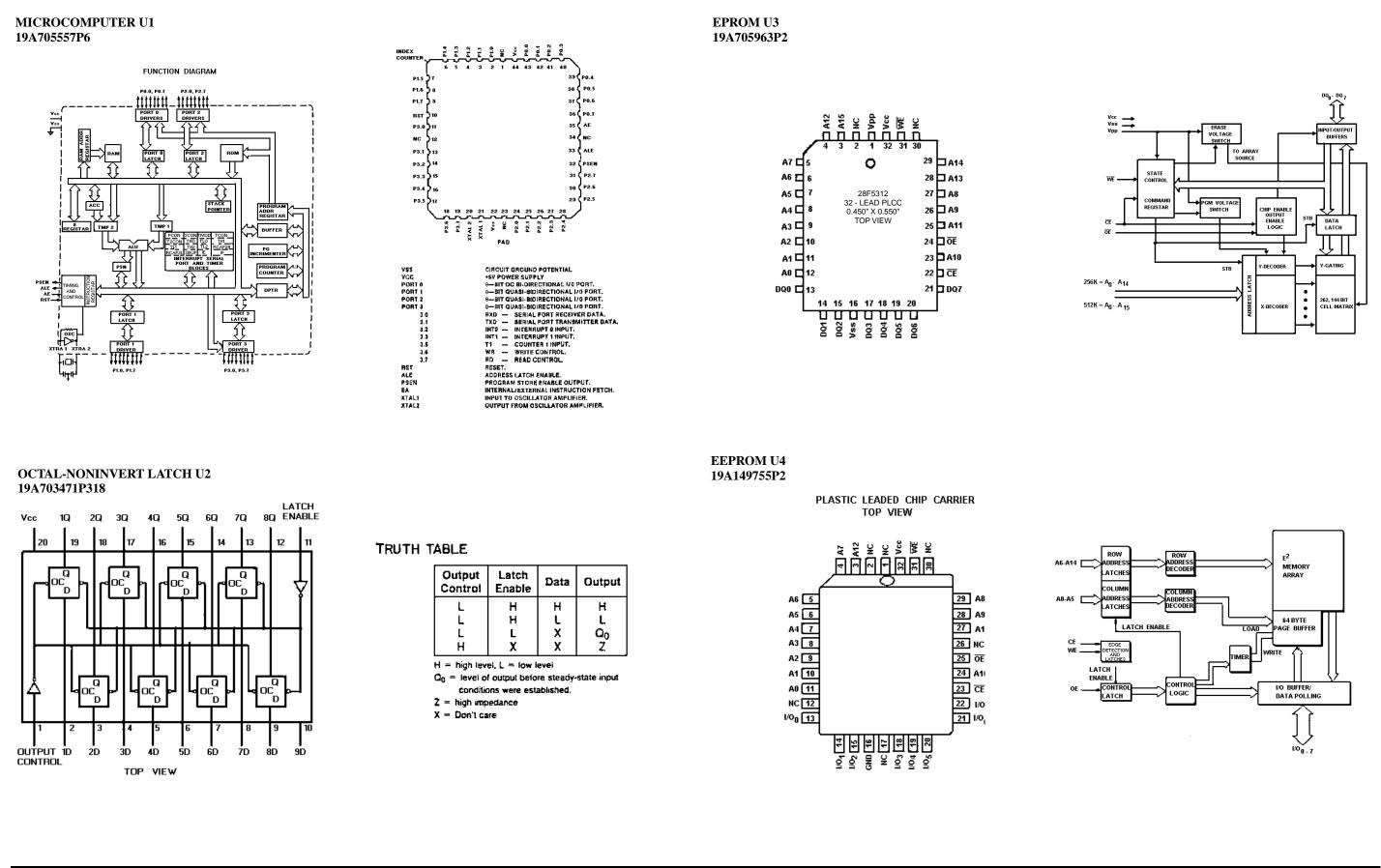
Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Paris List for the descriptions of perits affected by these revisions.

REV. A -	MICROCOMPUTER BOARD 19D903865G1 MICROCOMPUTER BOARD 19D903865G3 MICROCOMPUTER BOARD 19D903865G4 This revision removed pull-up resistor R144 to adjust voltage drop due to analog mux on the [/O Board. R144 was 19B800607P103 - Metal film, 10K ohms ±10, 1/8 w.
REV. B -	MICROCOMPUTER BOARD 19D903865G1 MICROCOMPUTER BOARD 19D903865G3 MICROCOMPUTER BOARD 19D903865G4 This revision added pull-up resistor R144 (19B800607P473, 47K ohms) to insure sufficient pull-up current for U1-7 (AUDICMUX).
	This revision also changed Flash Memory EPROM U3 software to 19A705710015 on the 19D902865Gl board and to 19A149935G4 on the 19D902865G3 board to correct T99 tone interdigit time.
	U3 was 19A705710G14 - EPROM KIT. (Group 1).
	U3 was 19A149935G3 - EPROM KIT. (Group 3).
REV. C -	MICROCOMPUTER BOARD 19D903865G1
	MICROCOMPUTER BOARD 19D903865G3
	MICROCOMPUTER BOARD 19D903865G4
	Adds a preset circuit to the power switch flip-flop.
	Added C96, 10µF 16VDC (19A705205P6)
	Added R140, 150 K ohm (19B800607P154)
	Changed R31 from 2.7 K ohms (19B800607P272) to 470 ohms

(19B800607P471). REV. D - MICROCOMPUTER BOARD 19D903865G1

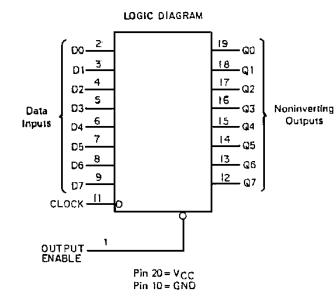
Corrrect problems in flash programming software.

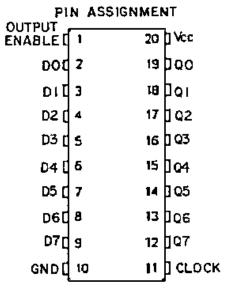
#### LBI-38726

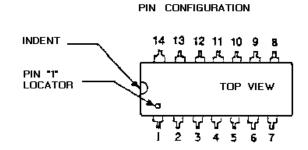


# IC DATA

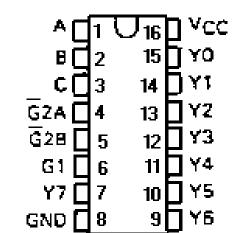
OCTAL DTA FLIP-FLOP U5 & U6 19A704380P316

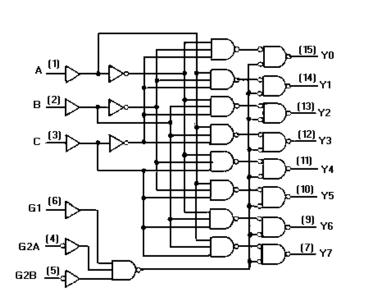






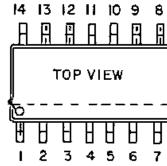
**DECODE/DEMUX U7** 19A703471P320

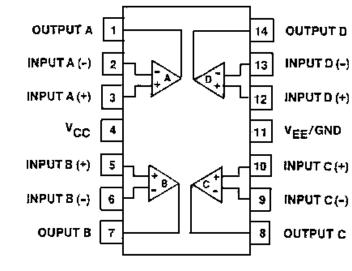




FUNCTION TABLE

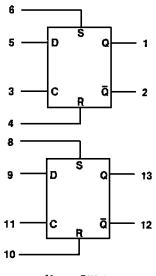
	ENABLE INPUTS			SELECT			OUTPUTS						
G1	G2A	ĞΖΒ	С	в	A	YO	۲١	Y2	Υ3	٧4	¥5	YG	¥7
x	н	X	х	X	X	н	н	н	н	н	Н	н	н
X	x	н	x	x	x	н	н	н	н	н	н	н	н
ι	x	x	х	x	x	н	н	н	н	н	н	н	н
н	L	L	ι	Ł	ι	ι	н	н	н	H	н	н	н
к	L	L	L	L	н	н	٤	н	н	н	н	H	Ħ
н	L	L	L	н	ι	н	н	Ļ	н	н	н	н	н
н	L	L	L	н	н	к	н	н	L	Ħ	н	Н	н
н	ι	L	н	L	L	н	н	н	к	L	н	н	н
н	L	Ł	н	L	н	н	н	н	н	н	ι	н	н
н	£	t.	н	н	ι	н	н	н	н	н	н	L	н
н	L	L	н	н	н.	н	н	н	н	н	н	н	L





# LBI-38726

#### DUAL DATA FLIP-FLOP U8 19A700029P509



V<sub>DD</sub> = PIN 14 VSS = PIN 7

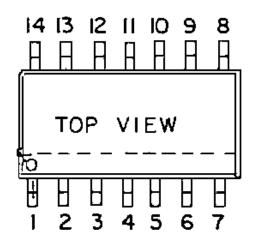


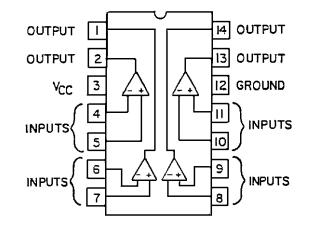
#### **OPERATIONAL AMPLIFIER U9** 19A702293P1

# LBI-38726

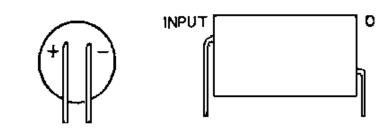
# IC DATA



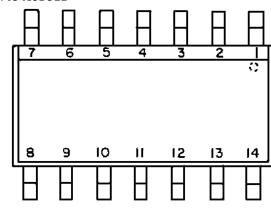




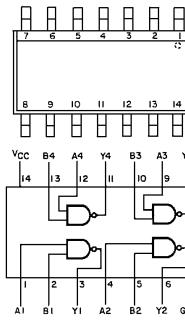
# ELECTROLUMINESCENT DRIVER U12 19A149417P2



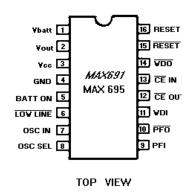
LOGIC OR GATE U13 19A703483P311

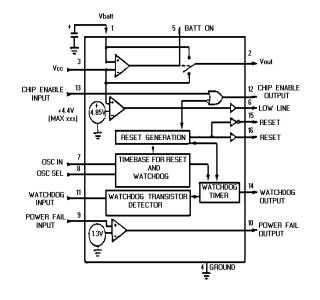


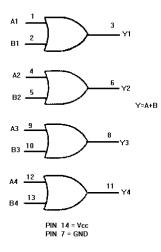
# LOGIC HAND GATE U14 19A703483P302



# SUPERVISORY CIRCUIT U11 19A149895P1









This page intentionally left blank

# LBI-38726